



BYG22A thru BYG22D

Vishay General Semiconductor

Ultrafast Avalanche SMD Rectifier



DO-214AC (SMA)

FEATURES

- Low profile package
- Ideal for automated placement
- Glass passivated junction
- Low reverse current
- Low forward voltage
- Soft recovery characteristic
- Ultra fast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 A
V_{RRM}	50 V to 200 V
I_{FSM}	35 A
I_R	1.0 μ A
V_F	1.1 V
t_{rr}	25 ns
E_R	20 mJ
T_J max.	150 °C

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214AC (SMA)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for highreliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS ($T_A = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	BYG22A	BYG22B	BYG22D	UNIT
Device marking code		BYG22A	BYG22B	BYG22D	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	V
Average forward current	$I_{F(AV)}$	2.0			A
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I_{FSM}	35			A
Pulse energy in avalanche mode, non repetitive (inductive load switch off) $I_{(BR)R} = 1$ A, $T_J = 25$ °C	E_R	20			mJ
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150			°C



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	BYG22A	BYG22B	BYG22D	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 1.0 A I _F = 2.0 A	T _J = 25 °C	V _F		1.0 1.1		V
Maximum reverse current	V _R = V _{RRM}	T _J = 25 °C T _J = 100 °C	I _R		1 10		μA
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}		25		ns

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)						
PARAMETER	SYMBOL	BYG22A	BYG22B	BYG22D	UNIT	
Maximum thermal resistance - junction lead $T_L = \text{const.}$	$R_{\theta JL}$		25		$^{\circ}\text{C/W}$	
Maximum thermal resistance - junction ambient	$R_{\theta JA}$		150 ⁽¹⁾ 125 ⁽²⁾ 100 ⁽³⁾		$^{\circ}\text{C/W}$	

Notes:

- (1) Mounted on epoxy-glass hard tissue
- (2) Mounted on epoxy-glass hard tissue, 50 mm² 35 μm Cu
- (3) Mounted on Al-oxide-ceramic (Al_2O_3), 50 mm² 35 μm Cu

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
BYG22A-E3/TR	0.064	TR	1800	7" diameter plastic tape and reel
BYG22A-E3/TR3	0.064	TR3	7500	13" diameter plastic tape and reel
BYG22AHE3/TR ⁽¹⁾	0.064	TR	1800	7" diameter plastic tape and reel
BYG22AHE3/TR3 ⁽¹⁾	0.064	TR3	7500	13" diameter plastic tape and reel

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

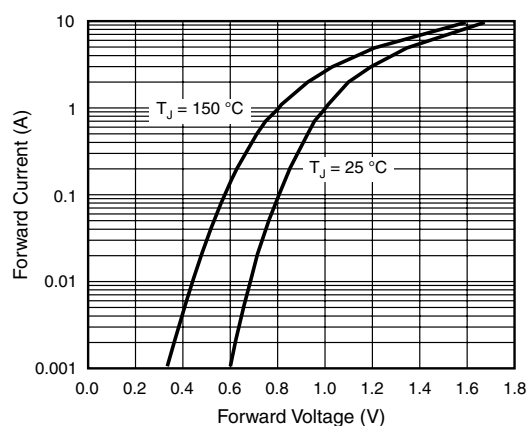


Figure 1. Forward Current vs. Forward Voltage

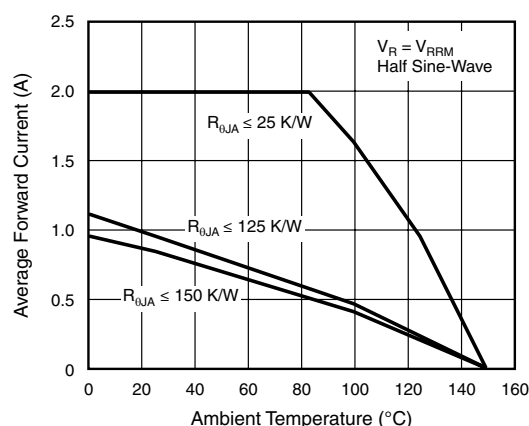


Figure 2. Max. Average Forward Current vs. Ambient Temperature



BYG22A thru BYG22D

Vishay General Semiconductor

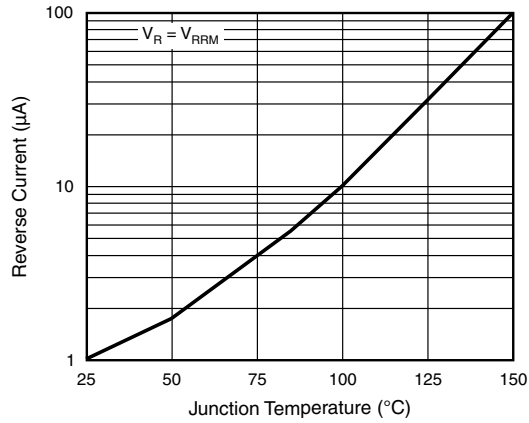


Figure 3. Reverse Current vs. Junction Temperature

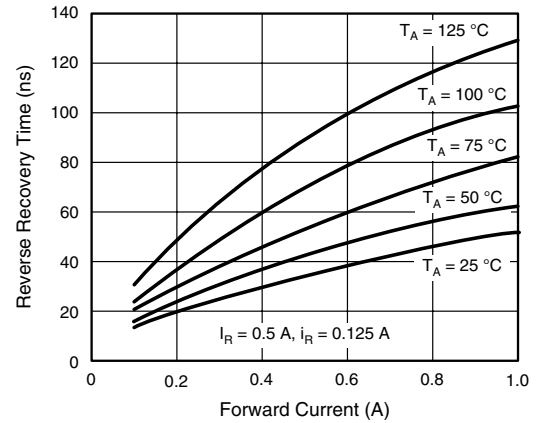


Figure 6. Max. Reverse Recovery Time vs. Forward Current

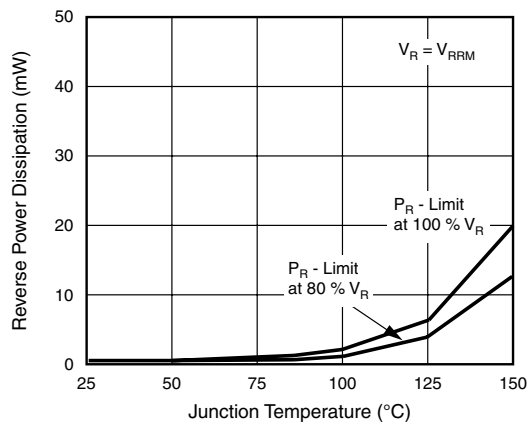


Figure 4. Max. Reverse Power Dissipation vs. Junction Temperature

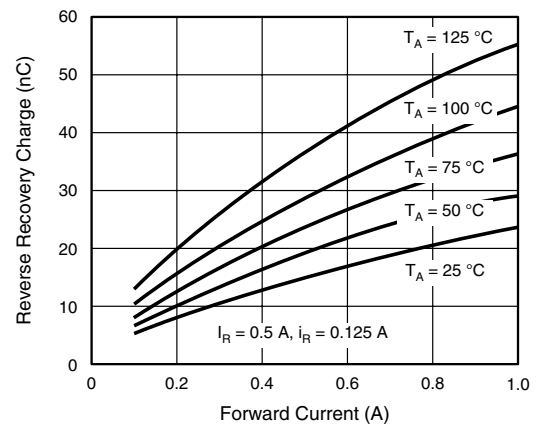


Figure 7. Max. Reverse Recovery Charge vs. Forward Current

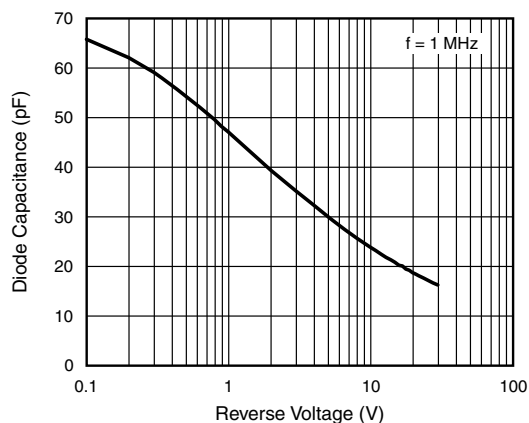


Figure 5. Diode Capacitance vs. Reverse Voltage

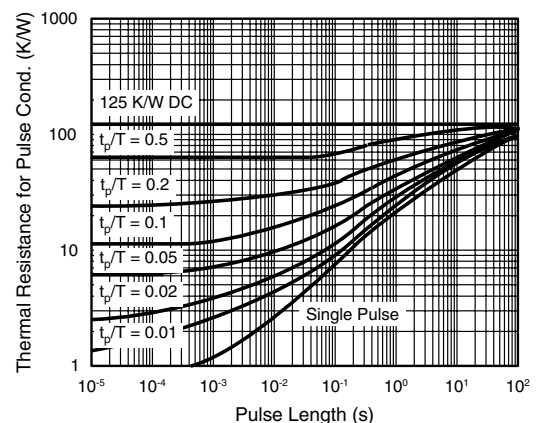


Figure 8. Thermal Response

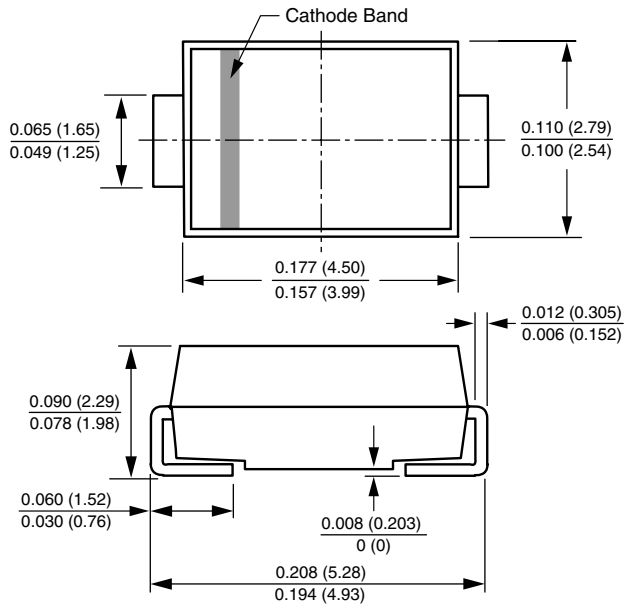
BYG22A thru BYG22D

Vishay General Semiconductor

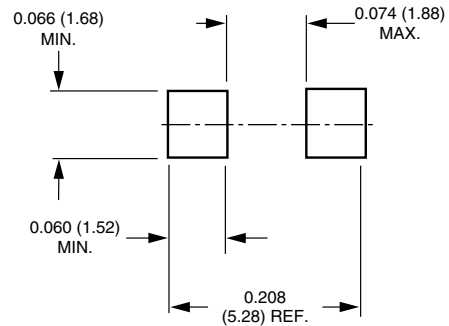


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AC (SMA)



Mounting Pad Layout





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All product specifications and data are subject to change without notice.

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